Peripheral/Power Drivers

DH0016CN*
DH0017CN*(SH2200P)
DH0018CN*

high voltage high current drivers

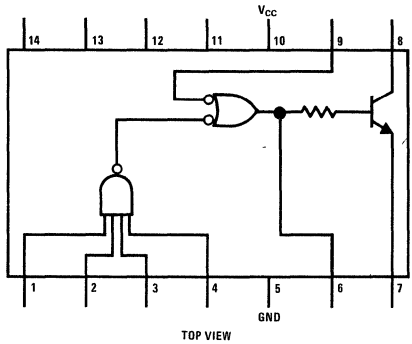
general description

This high-voltage, high-current driver family consists of hybrid integrated circuits which provide a wide range of output currents and output voltages. Applications include driving lamps, relays, cores, and other devices requiring up to 500 mA and withstanding voltages up to 100V. Logic flexibility is provided through a 4-input NAND gate, a NOR input and an input which bypasses the gating and connects to the base of the output transistor.

*Previously called NH0016CN, NH0017CN, NH0018CN

logic diagram

Dual-In-Line Package



TOP VIEW

ordering information

NSC DESIGNATION	SH DESIGNATION	SEE PACKAGE	OUTPUT CHARACTERISTICS	
			Maximum Standoff Voltage	Current
DH0016CN	N/A	21	70V	250 mA
DH0017CN	SH2200P	21	50V	500 mA
DH0018CN	N/A	21	100V	500 mA

absolute maximum ratings

V_{CC}		8V
Input Voltage		8V
Collector Voltage	DH0016CN	70V
	DH0017CN	50V
	DH0018CN	100V
Output Surge Current	DH0016CN	1.0A
	DH0017CN & DH0018CN	2.0A
Power Dissipation		455mW
Operating Temperature Range		0°C to +70°C
Storage Temperature		−65°C to +150°C

electrical characteristics

TEST NO.	PIN 1	PIN 2	PIN 3	PIN 4	PIN 5	PIN 6	PIN 7	PIN 8	PIN 9	PIN 10	SENSE	LIMITS MIN	LIMITS MAX
2	V_{IH}	V_{IH}	V_{IH}	V_{IH}	GND		GND	I_{OL1}		V_{CC}	V_8		V_{OL1}
3	V_{IL}				GND		GND	I_{OL1}	V_{IL}	V_{CC}	V_8		V_{OL1}
4		V_{IL}			GND		GND	I_{OL1}	V_{IL}	V_{CC}	V_8		V_{OL1}
5			V_{IL}		GND		GND	I_{OL1}	V_{IL}	V_{CC}	V_8		V_{OL1}
6				V_{IL}	GND		GND	I_{OL1}	V_{IL}	V_{CC}	V_8		V_{OL1}
7	V_{IL}				GND	I_{OL2}				V_{CC}	V_6		V_{OL2}
8		V_{IL}			GND	I_{OL2}				V_{CC}	V_6		V_{OL2}
9			V_{IL}		GND	I_{OL2}				V_{CC}	V_6		V_{OL2}
10				V_{IL}	GND	I_{OL2}				V_{CC}	V_6		V_{OL2}
11				GND	GND	I_{OL2}			V_{IH}	V_{CC}	V_6		V_{OL2}
12	V_R	GND	GND	GND	GND					V_{CC}	I_1		I_R
13	GND	V_R	GND	GND	GND					V_{CC}	I_2		I_R
14	GND	GND	V_R	GND	GND					V_{CC}	I_3		I_R
15	GND	GND	GND	V_R	GND					V_{CC}	I_4		I_R
16					GND				V_R	V_{CC}	I_9		I_R
17	V_F	V_R	V_R	V_R	GND					V_{CC}	I_1		$-I_F$
18	V_R	V_F	V_R	V_R	GND					V_{CC}	I_2		$-I_F$
19	V_R	V_R	V_F	V_R	GND					V_{CC}	I_3		$-I_F$
20	V_R	V_R	V_R	V_F	GND					V_{CC}	I_4		$-I_F$
21				GND	GND				V_F	V_{CC}	I_9		$-I_F$
22					GND		GND			V_{CC}	V_6	V_{OH1}	
23	GND				GND	I_{OL3}	GND	V_{OX}		V_{CC}	I_8		I_{OX}
24					GND					V_{PD}	I_{10}		I_{PD}
25	GND				GND				GND	V_{MAX}	I_{10}		I_{MAX}

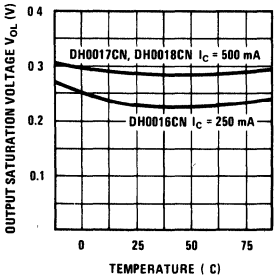
forcing functions

SYMBOL	0°C	+25°C	+70°C	UNITS
V_{CC}	5.0	5 0	5.0	V
V_{PD}		5.0		V
V_{MAX}		8.0		V
V_{IL}	0.85	0.85	0.85	V
V_{IH}	1 9	1.8	1.6	V
V_R	4.5	4.5	4.5	V
V_F	0.45	0.45	0.45	V
V_{OX} (DH0016CN)		70	70	V
V_{OX} (DH0017CN)		50	50	V
V_{OX} (DH0018CN)		100	100	V
I_{OL1} (DH0017CN, DH0018CN)	500	500	500	mA
I_{OL1} (DH0016CN)	250	250	250	mA
I_{OL2}	16	16	16	mA
I_{OL3}		8.0		mA

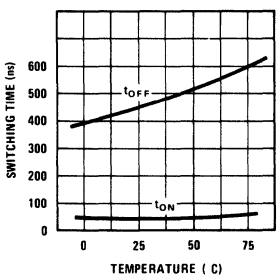
test limits

SYMBOL	0°C	+25°C	+70°C	UNITS
V_{OL1}	0.6	0.6	0.6	V
V_{OL2}	0.45	0.45	0.45	V
V_{OH1}	1.95	1.85	1.65	V
I_R		60	60	μA
$-I_F$	1.6	1.6	1.6	mA
I_{OX}		5.0	200	μA
I_{PD}		12.2		mA
I_{MAX}		10		mA

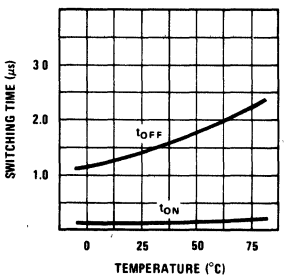
Typical Output Voltages vs Temperature



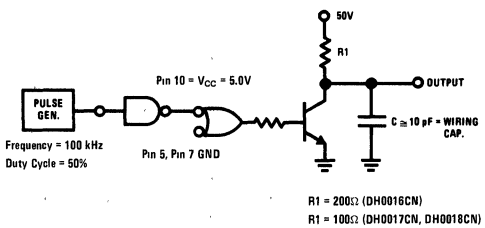
Typical Switching Times I_C = 250 mA
DH0016CN



Typical Switching Times I_C = 500 mA
DH0017CN, DH0018CN



switching time test circuit



R1 = 200Ω (DH0016CN)
R1 = 100Ω (DH0017CN, DH0018CN)

switching time waveform